Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

Contact us

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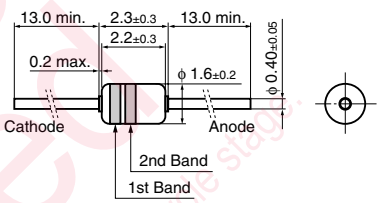
MA2C195 (MA195)

Silicon epitaxial planar type

For switching circuits

Unit: mm



1: Cathode
2: Anode
DO-34-A1 Package

■ Features

- Low forward dynamic resistance r_f
- Small terminal capacitance C_t

■ Absolute Maximum Ratings $T_a = 25°C$

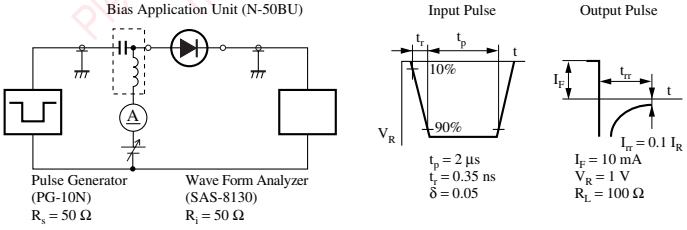
Parameter	Symbol	Rating	Unit
Reverse voltage	V_R	35	V
Repetitive peak reverse voltage	V_{RRM}	35	V
Forward current (Average)	$I_{F(AV)}$	100	mA
Repetitive peak forward current	I_{FRM}	225	mA
Non-repetitive peak forward surge current *	I_{FSM}	500	mA
Junction temperature	T_j	200	°C
Storage temperature	T_{stg}	−55 to +200	°C

Note) ∗: t = 1 s

■ Electrical Characteristics $T_a = 25°C \pm 3°C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Forward voltage	V_F	I_F = 100 mA			1.2	V
Reverse voltage	V_R	I_R = 100 µA	35			V
Reverse current	I_{R1}	V_R = 15 V			5	nA
	I_{R2}	V_R = 30 V			10	
	I_{R3}	V_R = 35 V, T_a = 150°C			100	µA
Terminal capacitance	C_t	V_R = 0 V, f = 1 MHz			4	pF
Forward dynamic resistance	r_f	I_F = 3 mA, f = 30 MHz			2.5	Ω
Reverse recovery time *	t_{rr}	I_F = 10 mA, V_R = 1 V I_{rr} = 0.1 I_R, R_L = 100 Ω			0.20	ms

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
2. Absolute frequency of input and output is 2.5 kHz.
3. ∗: t_{rr} measurement circuit

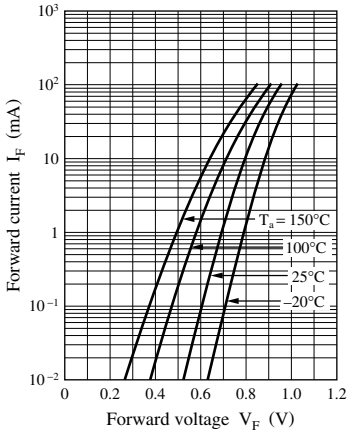


■ Cathode Indication

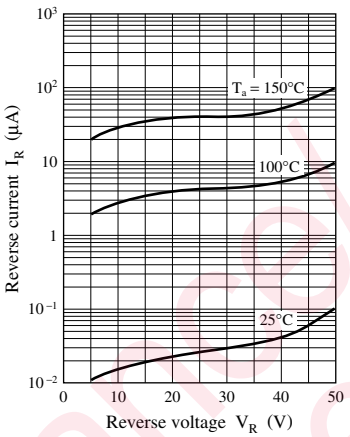
Type No.		
Color	1st Band	White
	2nd Band	White

Note) The part number in the parenthesis shows conventional part number.

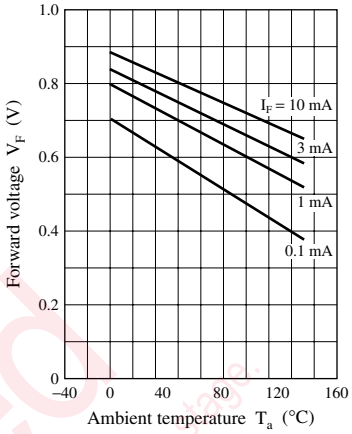
I_F — V_F



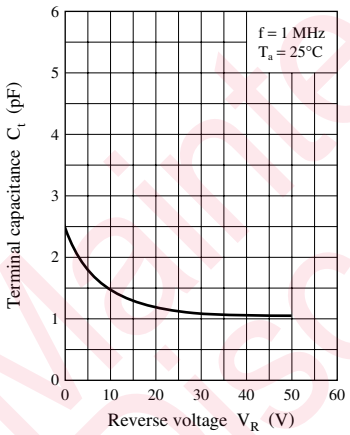
I_R — V_R



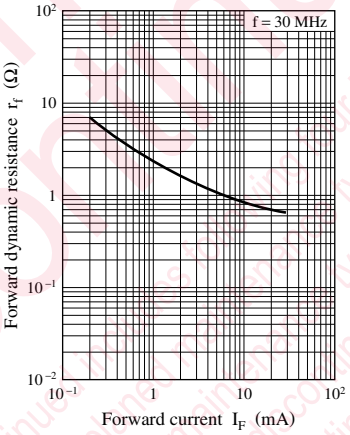
V_F — T_a



C_t — V_R



r_f — I_F



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